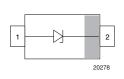


## Vishay Semiconductors

## **Single ESD-Protection Diode in SOD-523**





#### **FEATURES**

- Single-line ESD-protection
- ESD-immunity acc. IEC 61000-4-2 ± 30 kV contact discharge ± 30 kV air discharge
- Typ. capacitance = 130 pF
- Leakage current  $I_R < 1 \mu A (V_R = 5 V)$
- e3 Sn

· Material categorization: For definitions of compliance please see www.vishav.com/doc?99912









#### **MARKING** (example only)



Bar = cathode marking

X = date code

Y = type code (see table below)

ORDERING INFORMATION					
DEVICE NAME	ORDERING CODE	TAPED UNITS PER REEL	MINIMUM ORDER QUANTITY		
VESD05A1-02V	VESD05A1-02V-G-08	3000 (8 mm tape on 7" reel)	3000		
	VESD05A1-02V-G-18	10 000 (8 mm tape on 13" reel)	10 000		

PACKAGE DATA						
DEVICE NAME	PACKAGE NAME	TYPE CODE	WEIGHT	MOLDING COMPOUND FLAMMABILITY RATING	MOISTURE SENSITIVITY LEVEL	SOLDERING CONDITIONS
VESD05A1-02V	SOD-523	. Н	1.4 mg	UL 94 V-0	MSL level 1 (according J-STD-020)	260 °C/10 s at terminals

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	TEST CONDITIONS	VALUE	UNIT			
Peak pulse current	Acc. IEC 61000-4-5, 8/20 μs/single shot	I <sub>PPM</sub>	16	Α		
Peak pulse power	Acc. IEC 61000-4-5, 8/20 μs/single shot	P <sub>PP</sub>	192	W		
ESD immunity	Contact discharge acc. IEC 61000-4-2; 10 pulses	V	± 30	kV		
	Air discharge acc. IEC 61000-4-2; 10 pulses	V <sub>ESD</sub>	± 30	kV		
Operating temperature	Junction temperature	$T_J$	- 40 to + 125	°C		
Storage temperature		T <sub>stg</sub>	- 55 to + 150	ů		



## Vishay Semiconductors

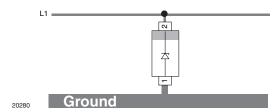
### **BIAs-MODE** (bidirectional asymmetrical protection mode)

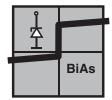
With the VESD05A1-02V one signal- or data-lines (L1) can be protected against voltage transients. With pin 1 connected to ground and pin 2 connected to a signal- or data-line which has to be protected. As long as the voltage level on the data- or signal-line is between 0 V (ground level) and the specified maximum reverse working voltage (V<sub>RWM</sub>) the protection diode between data line and ground offers a high isolation to the ground line. The protection device behaves like an open switch. As soon as any positive transient voltage signal exceeds the break through voltage level of the protection diode, the diode

becomes conductive and shorts the transient current to ground. Now the protection device behaves like a closed switch. The clamping voltage (V<sub>C</sub>) is defined by the breakthrough voltage (V<sub>BR</sub>) level plus the voltage drop at the series impedance (resistance and inductance) of the protection device.

Any negative transient signal will be clamped accordingly. The negative transient current is flowing in the forward direction of the protection diode. The low forward voltage (V<sub>F</sub>) clamps the negative transient close to the ground level.

Due to the different clamping levels in forward and reverse direction the VESD05A1-02V clamping behaviour is bidirectional and asymmetrical (BiAs).



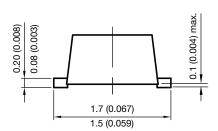


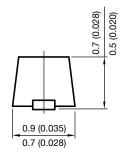
#### **ELECTRICAL CHARACTERISTICS**

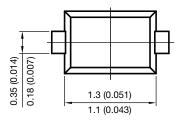
(T <sub>amb</sub> = 25 °C, unless otherwise specified)								
PARAMETER	TEST CONDITIONS/REMARKS	SYMBOL	MIN.	TYP.	MAX.	UNIT		
Protection paths	Number of lines which can be protected	N <sub>channel</sub>	ı	-	1	lines		
Reverse stand off voltage	Max. reverse working voltage	$V_{RWM}$	ı	-	5	V		
Reverse voltage	at I <sub>R</sub> = 1 μA	$V_R$	5	-	-	V		
Reverse current	at V <sub>R</sub> = 5 V	I <sub>R</sub>	-	< 0.1	1	μΑ		
Reverse breakdown voltage	at I <sub>R</sub> = 1 mA	$V_{BR}$	6	6.8	7.5	V		
Reverse clamping voltage	at I <sub>PP</sub> = 1 A; 8/20 µs test pulse	$V_{C}$	ı	7.2	8.5	V		
	at I <sub>PP</sub> = I <sub>PPM</sub> = 16 A; 8/20 µs test pulse	$V_{C}$	ı	10.5	12	V		
	at I <sub>PP</sub> = 0.2 A; 8/20 µs test pulse	$V_{F}$	-	0.88	1.1	V		
Forward clamping voltage	at I <sub>PP</sub> = 1 A; 8/20 µs test pulse	$V_{F}$	-	1	1.5	V		
	at I <sub>PP</sub> = I <sub>PPM</sub> = 16 A; 8/20 µs test pulse	$V_{F}$	-	3.2	4.5	V		
Capacitance	at $V_R = 0 V$ ; $f = 1 MHz$	C <sub>D</sub>	-	130	150	pF		
	at V <sub>R</sub> = 2.5 V; f = 1 MHz	$C_D$	-	76	-	pF		

# Vishay Semiconductors

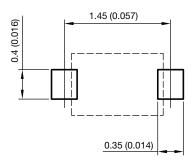
#### PACKAGE DIMENSIONS in millimeters (Inches): SOD-523







foot print recommendation:



Document no.: S8-V-3880.02-001 (4)

Rev. h - Date: 13. Oct. 2010

16864



## **Legal Disclaimer Notice**

Vishay

### **Disclaimer**

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and/or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

## **Material Category Policy**

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as RoHS-Compliant fulfill the definitions and restrictions defined under Directive 2011/65/EU of The European Parliament and of the Council of June 8, 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment (EEE) - recast, unless otherwise specified as non-compliant.

Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as Halogen-Free follow Halogen-Free requirements as per JEDEC JS709A standards. Please note that some Vishay documentation may still make reference to the IEC 61249-2-21 definition. We confirm that all the products identified as being compliant to IEC 61249-2-21 conform to JEDEC JS709A standards.

Revision: 02-Oct-12 Document Number: 91000